

# Ultra Series<sup>™</sup> Crystal Oscillator (VCXO) Si566 Data Sheet

## Ultra Low Jitter Dual Any-Frequency VCXO (100 fs), 0.2 to 3000 MHz

The Si566 Ultra Series<sup>™</sup> voltage-controlled crystal oscillator utilizes Silicon Laboratories' advanced 4<sup>th</sup> generation DSPLL® technology to provide an ultra-low jitter, low phase noise clock at two selectable frequencies. The device is factoryprogrammed to provide any two selectable frequencies from 0.2 to 3000 MHz with <1 ppb resolution and maintains exceptionally low jitter for both integer and fractional frequencies across its operating range. On-chip power supply filtering provides industry-leading power supply noise rejection, simplifying the task of generating low jitter clocks in noisy systems that use switched-mode power supplies. Offered in industry-standard footprints, the Si566 has a dramatically simplified supply chain that enables Silicon Labs to ship custom frequency samples 1-2 weeks after receipt of order. Unlike a traditional XO, where a different crystal is required for each output frequency, the Si566 uses one simple crystal and a DSPLL IC-based approach to provide the desired output frequencies. The Si566 is factory-configurable for a wide variety of user specifications, including frequency, output format, and OE pin location/polarity. Specific configurations are factory-programmed at time of shipment, eliminating the long lead times associated with custom oscillators.

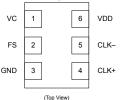




5 x 7 mm and 3.2 x 5 mm 2.5 x 3.

2.5 x 3.2 mm

#### **Pin Assignments**

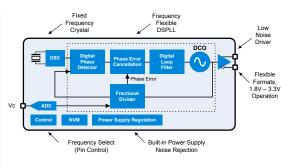


#### KEY FEATURES

- Available with any two selectable frequencies from 200 kHz to 3000 MHz
- Ultra low jitter: 100 fs RMS typical (12 kHz – 20 MHz)
- Excellent PSNR and supply noise immunity: –80 dBc Typ
- 3.3 V, 2.5 V and 1.8 V  $V_{\text{DD}}$  supply operation from the same part number
- LVPECL, LVDS, CML, HCSL, CMOS, and Dual CMOS output options
- 2.5x3.2, 3.2x5, 5x7 mm package options
- · Samples available with 1-2 week lead times

#### APPLICATIONS

- 100G/200G/400G OTN, coherent optics
- 10G/25G/40G/100G Ethernet
- · 56G/112G PAM4 clocking
- 3G-SDI/12G-SDI/24G-SDI broadcast video
- Servers, switches, storage, NICs, search acceleration
- Test and measurement
- FPGA/ASIC clocking



Pin #	Descriptions
1	VC = Voltage Control Pin
2	FS = Frequency Select
3	GND = Ground
4	CLK+ = Clock output
5	CLK- = Complementary clock output. Not used for CMOS.
6	VDD = Power supply

## 1. Ordering Guide

The Si566 VCXO supports a variety of options including frequency, output format, and OE pin location/polarity, as shown in the chart below. Specific device configurations are programmed into the part at time of shipment, and samples are available in 1-2 weeks. Silicon Laboratories provides an online part number configuration utility to simplify this process. Refer to www.silabs.com/oscillators to access this tool and for further ordering instructions.

VCXO Series	Description		C	ode VC	Pin	FS Pin			Pa	ckage	]	Temperatu	ure Grade		
566	Dual Frequency V	/CXO		A Pi	n 1	Pin 2		Α	5×	7 mm	G	-40 to	85 °C		
							_	В	3.2	x5 mm	]				
								С	2.5×	3.2 mm	]				
	[	566	Α		- -	] [-]	-	-][-	.][	- A	C	G F Device Revi			
Signal Format	VDD Range	Order	Γ									Code	Reel		
Signari ormat	VDD Range	Option		<b>T</b>		04-1-11						R	Tape and Ree		
LVPECL	2.5, 3.3 V	A			-	ure Stabil						<blank></blank>	Coil Tape		
LVDS	1.8, 2.5, 3.3 V	В		Vc Tu		Min APF	א [± ppm	] at VD							
CMOS	1.8, 2.5, 3.3 V	С		Slo Kv [pp	•	3.3V	2.5V			Frequ Co	-	Des	cription		
CML	1.8, 2.5, 3.3 V	D	A			20				0000				Two unique frequencies can	
HCSL	1.8, 2.5, 3.3 V	E	В	-	-	40	20						in the supported		
Dual CMOS (In-Phase)	1.8, 2.5, 3.3 V	F	C		-	70	40	20		~~~~~	~~~	range of the selected signal format. Either frequency can			
Dual CMOS			D	15	0	115	75	45		XXXX	~~~	assigned to FS=0 or FS=1. A six digit numeric code will be assigned for the specific combination of frequencies.			
(Complementary	) 1.8, 2.5, 3.3 V	G	E	18	0	145	100	65							
HCSL-Fast	1.8, 2.5, 3.3 V	Н	F	22	5	190	135	85							
Custom	1.8, 2.5, 3.3 V	Х	<u> </u>			I				L					

#### Notes:

1. Contact Silicon Labs for non-standard configurations.

- 2. Create custom part numbers at www.silabs.com/oscillators.
- 3. Min Absolute Pull Range (APR) includes temp stability, initial accuracy, load pulling, VDD variation, and 20 year aging at 70 °C.
  - a. For best jitter and phase noise performance, always choose the smallest Kv that meets the application's minimum APR requirements. Unlike SAW-based solutions which require higher Kv values to account for their higher temperature dependence, the Si56x series provides lower Kv options to minimize noise coupling and jitter in real-world PLL designs.
  - b. APR is the ability of a VCXO to track a signal over the product lifetime. A VCXO with an APR of ±20 ppm is able to lock to a clock with a ±20 ppm stability over 20 years over all operating conditions.
  - c. APR (±) = (0.5 x VDD x tuning slope) (initial accuracy + temp stability + load pulling + VDD variation + aging).
  - d. Minimum APR values noted above include absolute worst case values for all parameters.
  - e. See application note, "AN266: VCXO Tuning Slope (Kv), Stability, and Absolute Pull Range (APR)" for more information.

#### 1.1 Technical Support

Frequently Asked Questions (FAQ)	www.silabs.com/Si566-FAQ
Oscillator Phase Noise Lookup Utility	www.silabs.com/oscillator-phase-noise-lookup
Quality and Reliability	www.silabs.com/quality
Development Kits	www.silabs.com/oscillator-tools

## 2. Electrical Specifications

#### Table 2.1. Electrical Specifications

 $V_{DD}$  = 1.8 V, 2.5 or 3.3 V  $\pm$  5%,  $T_A$  = –40 to 85 °C

Parameter	Symbol	Test Condition/Comment	Min	Тур	Max	Unit
Temperature Range	T <sub>A</sub>		-40		85	°C
Frequency Range	F <sub>CLK</sub>	LVPECL, LVDS, CML	0.2		3000	MHz
		HCSL	0.2		400	MHz
		CMOS, Dual CMOS	0.2		250	MHz
Supply Voltage	V <sub>DD</sub>	3.3 V	3.135	3.3	3.465	V
Supply Current		2.5 V	2.375	2.5	2.625	V
		1.8 V	1.71	1.8	1.89	V
Supply Current	I <sub>DD</sub>	LVPECL (output enabled)	_	120	170	mA
		LVDS/CML (output enabled)	_	100	140	mA
		HCSL (output enabled)	_	95	140	mA
		HCSL-Fast (output enabled)	_	103	152	mA
		CMOS (output enabled)	_	95	145	mA
		Dual CMOS (output enabled)	_	105	155	mA
		Tristate Hi-Z (output disabled)	_	83	_	mA
Temperature Stability <sup>1</sup>		-40 to 85 °C	-20		20	ppm
Rise/Fall Time	T <sub>R</sub> /T <sub>F</sub>	LVPECL/LVDS/CML			350	ps
(20% to 80% V <sub>PP</sub> )		CMOS / Dual CMOS (C <sub>L</sub> = 5 pF)	-	0.5	1.5	ns
		HCSL, F <sub>CLK</sub> >50 MHz	_		550	ps
		HCSL-Fast, F <sub>CLK</sub> >50 MHz	_		275	ps
Duty Cycle	D <sub>C</sub>	All formats	45		55	%
Frequency Select (FS) <sup>2</sup>	V <sub>IH</sub>		0.7 × V <sub>DD</sub>		_	V
	V <sub>IL</sub>		_		0.3 × V <sub>DD</sub>	V
	T <sub>FS</sub>	Settling Time after FS Change	_		10	ms
Powerup Time	tosc	Time from 0.9 × $V_{DD}$ until output frequency ( $F_{CLK}$ ) within spec	-		10	ms
Powerup VDD Ramp Rate	V <sub>RAMP</sub>	Fastest V <sub>DD</sub> ramp rate allowed on startup	-		100	V/ms
LVPECL Output Option <sup>3</sup>	V <sub>OC</sub>	Mid-level	V <sub>DD</sub> – 1.42		V <sub>DD</sub> – 1.25	V
	Vo	Swing (diff, F <sub>CLK</sub> ≤ 1.5 GHz)	1.1		1.9	V <sub>PP</sub>
		Swing (diff, F <sub>CLK</sub> > 1.5 GHz) <sup>6</sup>	0.55		1.7	V <sub>PP</sub>

#### Si566 Data Sheet • Electrical Specifications

Parameter	Symbol	Test Condition/Comment	Min	Тур	Мах	Unit
LVDS Output Option <sup>4</sup>	V <sub>OC</sub>	Mid-level (2.5 V, 3.3 V VDD)	1.125	1.20	1.275	V
		Mid-level (1.8 V VDD)	0.8	0.9	1.0	V
	Vo	Swing (diff, F <sub>CLK</sub> ≤ 1.4 GHz)	0.6	0.7	0.9	V <sub>PP</sub>
		Swing (diff, $F_{CLK}$ > 1.4 GHz) <sup>6</sup>	0.25	0.5	0.8	V <sub>PP</sub>
HCSL Output Option <sup>5</sup> HCSL-Fast Output Option <sup>5</sup>	V <sub>OH</sub>	Output voltage high	660	800	850	mV
	V <sub>OL</sub>	Output voltage low	-150	0	150	mV
	$ \begin{array}{c c}                                    $	Crossing voltage	250	410	550	mV
CML Output Option (AC-Coupled)	Vo	Swing (diff, $F_{CLK} \le 1.5 \text{ GHz}$ )	0.6	0.8	1.0	V <sub>PP</sub>
		Swing (diff, F <sub>CLK</sub> > 1.5 GHz) <sup>6</sup>	0.3	0.55	0.9	V <sub>PP</sub>
CMOS Output Option	V <sub>OH</sub>	I <sub>OH</sub> = 8/6/4 mA for 3.3/2.5/1.8 V VDD	$0.85 \times V_{DD}$	—	—	V
	V <sub>OL</sub>	I <sub>OL</sub> = 8/6/4 mA for 3.3/2.5/1.8 V VDD	—		0.15 × V <sub>DD</sub>	V

#### Notes:

1. Min APR includes temperature stability, initial accuracy, load pulling, VDD variation, and aging for 20 yrs at 70 °C.

2. FS pin includes a 50 k $\Omega$  pull-up to VDD.

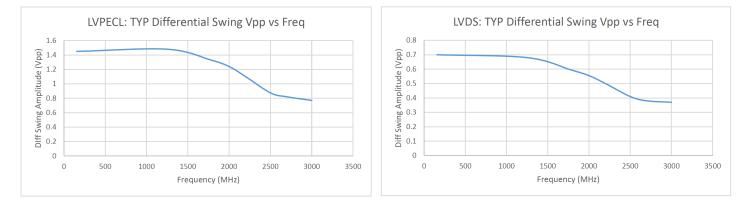
3. R<sub>term</sub> = 50  $\Omega$  to V<sub>DD</sub> – 2.0 V (see Figure 4.1). Additional DC current from the output driver will flow through the 50  $\Omega$  resistors, resulting in a shift in common mode voltage. The measurements in this table have accounted for this.

4.  $R_{term}$  = 100  $\Omega$  (differential) (see Figure 4.2).

5.  $R_{term}$  = 50  $\Omega$  to GND (see Figure 4.2).

6. Refer to the figure below for Typical Clock Output Swing Amplitudes vs Frequency.

#### Si566 Data Sheet • Electrical Specifications



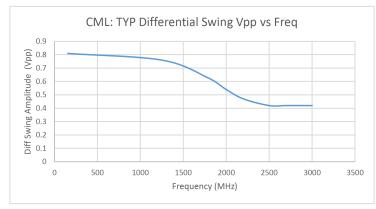


Figure 2.1. Typical Clock Output Swing Amplitudes vs. Frequency

### Table 2.2. V<sub>C</sub> Control Voltage Input

 $V_{DD}$  = 1.8, 2.5 or 3.3 V ± 5%,  $T_A$  = –40 to 85 °C

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Control Voltage Range	V <sub>C</sub>		0.1 x VDD	VDD/2	0.9 x VDD	V
Control Voltage Tuning Slope (Vc = 10% VDD to 90% VDD)	Κv	Positive slope, ordering option	60, 75, 105, 150, 180, 225		ppm/V	
Kv Variation	Kv_var		_	_	±10	%
Control Voltage Linearity	LVC	Best Straight Line fit	-1.5	±0.5	+1.5	%
Modulation Bandwidth	BW		_	10	_	kHz
Vc Input Impedance	ZVC		500	_	_	kΩ

#### Table 2.3. Clock Output Phase Jitter and PSNR

## $V_{DD}$ = 1.8 V, 2.5 or 3.3 V $\pm$ 5%, $T_A$ = –40 to 85 °C

Parameter	Symbol	Test Condition/Comment	Min	Тур	Max	Unit
Phase Jitter (RMS, 12 kHz - 20 MHz) <sup>1</sup> All Differential Formats, $F_{CLK} \ge 200 \text{ MHz}$	φJ	Kv = 60 ppm/V	_	100	150	fs
		Kv = 75 ppm/V	_	103		fs
		Kv = 105 ppm/V		110		fs
		Kv = 150 ppm/V	_	123	_	fs
		Kv = 180 ppm/V	_	132	_	fs
		Kv = 225 ppm/V	_	150	_	fs
Phase Jitter (RMS, 12 kHz - 20 MHz) <sup>1</sup> All Diff Formats, 100 MHz $\leq$ F <sub>CLK</sub> $<$ 200 MHz	φJ	Kv = 60 ppm/V	_	115	180	fs
		Kv = 75 ppm/V	_	118	_	fs
		Kv = 105 ppm/V	_	125	_	fs
		Kv = 150 ppm/V	_	138	_	fs
		Kv = 180 ppm/V	_	147	_	fs
		Kv = 225 ppm/V	_	165	_	fs
Phase Jitter (RMS, 12 kHz - 20 MHz) <sup>1</sup>	φJ	Kv = 60 ppm/V	_	110	130	fs
LVDS, F <sub>CLK</sub> = 156.25 MHz		Kv = 75 ppm/V	_	113	_	fs
		Kv = 105 ppm/V	_	120	_	fs
		Kv = 150 ppm/V	_	133	_	fs
		Kv = 180 ppm/V	_	142	_	fs
		Kv = 225 ppm/V	_	160	_	fs
Phase Jitter (RMS, 12 kHz - 20 MHz) <sup>1</sup> CMOS / Dual CMOS Formats	φJ	10 MHz ≤ F <sub>CLK</sub> < 250 MHz	_	200	_	fs

#### Si566 Data Sheet • Electrical Specifications

Parameter	Symbol	Test Condition/Comment	Min	Тур	Max	Unit
Spurs Induced by External Power Supply Noise, 50 mVpp Ripple. LVDS 156.25 MHz Output	PSNR	100 kHz sine wave		-83		dBc
		200 kHz sine wave		-83		
		500 kHz sine wave		-82		
		1 MHz sine wave		-85		
Note:						
1. Guaranteed by characterization. Jitter inclu	isive of any sp	ours.				

Offset Frequency (f)	156.25 MHz LVDS	200 MHz LVDS	644.53125 MHz LVDS	Unit
100 Hz	-73	-71	-60	
1 kHz	-102	-102	-93	
10 kHz	-130	–128	–118	
100 kHz	-141	–139	–129	dBc/Hz
1 MHz	–150	-148	–138	
10 MHz	–159	-160	–153	
20 MHz	-160	-162	-154	
Offset Frequency (f)	156.25 MHz LVPECL	200 MHz LVPECL	644.53125 MHz LVPECL	Unit
100 Hz	-72	-71	-60	
1 kHz	-103	-101	-92	
10 kHz	-130	–127	–117	
100 kHz	-142	–139	–129	dBc/Hz
1 MHz	–150	-148	–138	
10 MHz	-160	-162	-154	
20 MHz	–161	-162	–156	

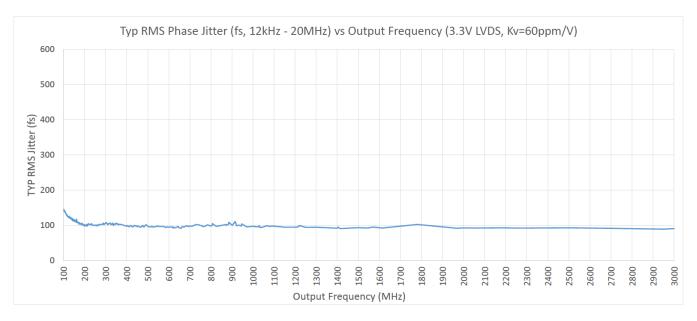


Figure 2.2. Phase Jitter vs. Output Frequency

Phase jitter measured with Agilent E5052 using a differential-to-single ended converter (balun or buffer). Measurements collected for >700 commonly used frequencies. Phase noise plots for specific frequencies are available using our free, online Oscillator Phase Noise Lookup Tool at www.silabs.com/oscillators.

#### Table 2.5. Environmental Compliance and Package Information

Parameter	Test Condition
Mechanical Shock	MIL-STD-883, Method 2002
Mechanical Vibration	MIL-STD-883, Method 2007
Solderability	MIL-STD-883, Method 2003
Gross and Fine Leak	MIL-STD-883, Method 1014
Resistance to Solder Heat	MIL-STD-883, Method 2036
Moisture Sensitivity Level (MSL): 3.2 x 5, 5 x 7 packages	1
Moisture Sensitivity Level (MSL): 2.5 x 3.2 package	2
Contact Pads: 3.2x5, 5x7 packages	Au/Ni (0.3 - 1.0 μm / 1.27 - 8.89 μm)
Contact Pads: 2.5x3.2 packages	Au/Pd/Ni (0.03 - 0.12 μm / 0.1 - 0.2 μm / 3.0 - 8.0 μm)

Note:

1. For additional product information not listed in the data sheet (e.g. RoHS Certifications, MDDS data, qualification data, REACH Declarations, ECCN codes, etc.), refer to our "Corporate Request For Information" portal found here: www.silabs.com/support/quality/Pages/RoHSInformation.aspx.

#### Table 2.6. Thermal Conditions<sup>1</sup>

#### Max Junction Temperature = 125° C

Package	Parameter	Symbol	Test Condition	Value	Unit
	Thermal Resistance Junction to Ambient	$\Theta_{JA}$	Still Air, 85 °C	72	°C/W
2.5 x 3.2 mm 6-pin DFN <sup>2</sup>	Thermal Parameter Junction to Board	$\Psi_{JB}$	Still Air, 85 °C	38	°C/W
	Thermal Parameter Junction to Top Center	$\Psi_{JT}$	Still Air, 85 °C	15	°C/W
	Thermal Resistance Junction to Ambient	Θ <sub>JA</sub>	Still Air, 85 °C	55	°C/W
3.2 × 5 mm 6-pin CLCC	Thermal Parameter Junction to Board	$\Psi_{JB}$	Still Air, 85 °C	20	°C/W
	Thermal Parameter Junction to Top Center	$\Psi_{JT}$	Still Air, 85 °C	20	°C/W
	Thermal Resistance Junction to Ambient	Θ <sub>JA</sub>	Still Air, 85 °C	53	°C/W
5 × 7 mm 6-pin CLCC	Thermal Parameter Junction to Board	$\Psi_{JB}$	Still Air, 85 °C	26	°C/W
	Thermal Parameter Junction to Top Center	$\Psi_{JT}$	Still Air, 85 °C	26	°C/W

#### Note:

1. Based on PCB Dimensions: 4.5" x 7", PCB Thickness: 1.6 mm, Number of Cu Layers: 4.

2. For best 2.5x3.2mm thermal performance, use 2 GND vias as shown in the Si5xxUC-EVB eval board layout

#### Table 2.7. Absolute Maximum Ratings<sup>1</sup>

Parameter	Symbol	Rating	Unit
Maximum Operating Temp.	T <sub>AMAX</sub>	95	°C
Storage Temperature	T <sub>S</sub>	-55 to 125	°C
Supply Voltage	V <sub>DD</sub>	-0.5 to 3.8	°C
Input Voltage	V <sub>IN</sub>	–0.5 to V <sub>DD</sub> + 0.3	V
ESD HBM (JESD22-A114)	НВМ	2.0	kV
Solder Temperature <sup>2</sup>	T <sub>PEAK</sub>	260	°C
Solder Time at T <sub>PEAK</sub> <sup>2</sup>	T <sub>P</sub>	20–40	sec

Notes:

1. Stresses beyond those listed in this table may cause permanent damage to the device. Functional operation specification compliance is not implied at these conditions. Exposure to maximum rating conditions for extended periods may affect device reliability.

2. The device is compliant with JEDEC J-STD-020.

Si566 Data Sheet • Dual CMOS Buffer

## 3. Dual CMOS Buffer

Dual CMOS output format ordering options support either complementary or in-phase signals for two identical frequency outputs. This feature enables replacement of multiple VCXOs with a single Si566 device.

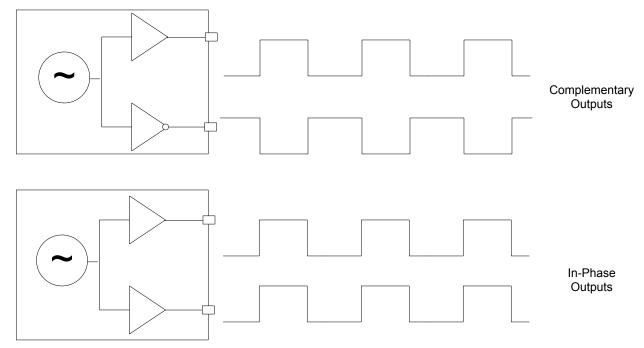
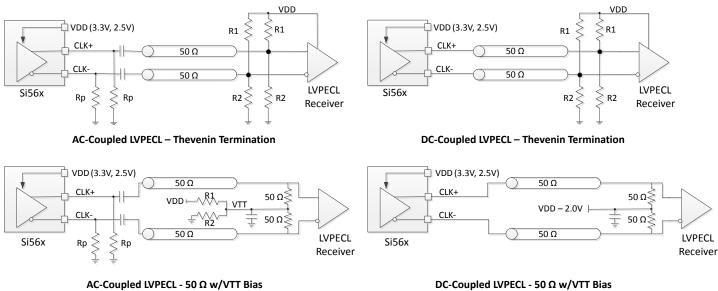


Figure 3.1. Integrated 1:2 CMOS Buffer Supports Complementary or In-Phase Outputs

## 4. Recommended Output Terminations

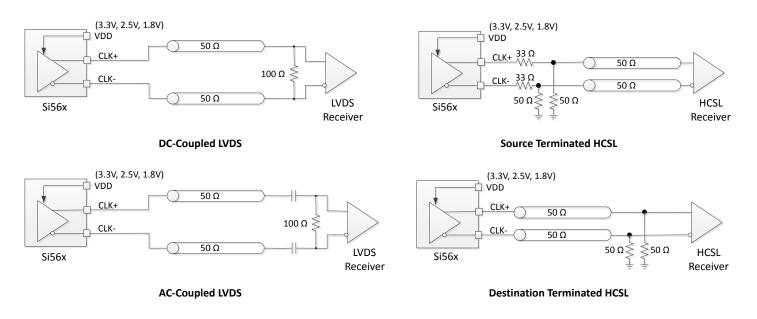
The output drivers support both AC-coupled and DC-coupled terminations as shown in figures below.



AC-Coupled LVPECL - 50 Ω w/VTT Bias

Figure 4.1.	LVPECL	Output	Terminations
1 19410 4.1.		Output	

		ed LVPECL esistor Values			DC-Coupled LVPECL mination Resistor Va	
VDD	R1	R2	Rp	VDD	R1	R2
3.3 V	82.5 Ω	127 Ω	130 Ω	3.3 V	127 Ω	82.5 Ω
2.5 V	62.5 Ω	250 Ω	90 Ω	2.5 V	250 Ω	62.5 Ω





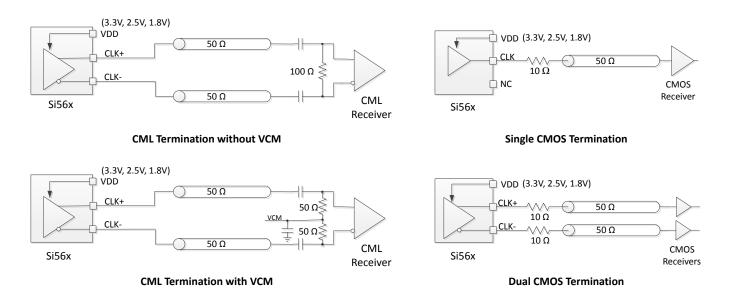


Figure 4.3. CML and CMOS Output Terminations

Si566 Data Sheet • Package Outline

## 5. Package Outline

#### 5.1 Package Outline (5×7 mm)

The figure below illustrates the package details for the 5×7 mm Si566. The table below lists the values for the dimensions shown in the illustration.

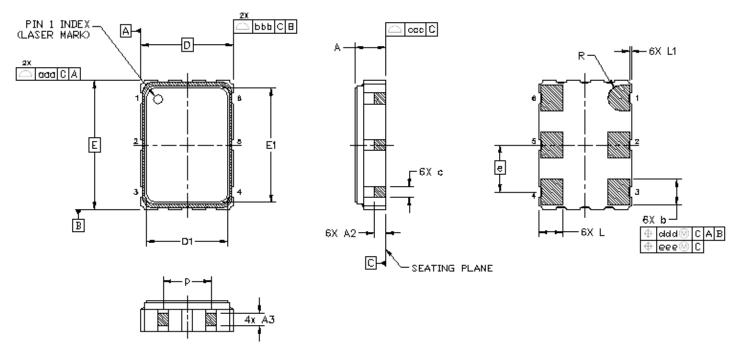


Figure 5.1. Si566 (5×7 mm) Outline Diagram

Table 5.1.	Package	Diagram	Dimensions	(mm)
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Dimension	Min	Nom	Max	Dimension	Min	Nom	Мах
А	1.13	1.28	1.43	L	1.17	1.27	1.37
A2	0.50	0.55	0.60	L1	0.05	0.10	0.15
A3	0.50	0.55	0.60	р	1.70	_	1.90
b	1.30	1.40	1.50	R		0.70 REF	
С	0.50	0.60	0.70	aaa	0.15		
D		5.00 BSC		bbb		0.15	
D1	4.30	4.40	4.50	ссс	0.08		
е		2.54 BSC		ddd 0.10			
E		7.00 BSC		eee	eee 0.05		
E1	6.10	6.20	6.30				

#### Notes:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

Si566 Data Sheet • Package Outline

#### 5.2 Package Outline (3.2×5 mm)

The figure below illustrates the package details for the 3.2×5 mm Si566. The table below lists the values for the dimensions shown in the illustration.

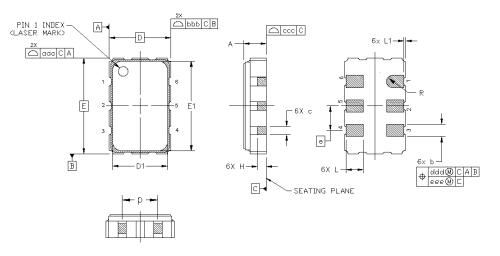


Figure 5.2. Si566 (3.2×5 mm) Outline Diagram

Table 5.2. Package Diagram Dimensions (mm)	Table 5.2.	Package	Diagram	Dimensions	(mm)
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Dimension	Min	Nom	Мах		
A	1.06	1.17	1.33		
b	0.54	0.64	0.74		
С	0.35	0.45	0.55		
D	3.20 BSC				
D1	2.55 2.60 2.65				
e	1.27 BSC				
E	5.00 BSC				
E1	4.35 4.40 4.45				
Н	0.45	0.55	0.65		
L	0.80	0.90	1.00		
L1	0.05	0.10	0.15		
р	1.36 1.46 1.56				
R	0.32 REF				
aaa	0.15				
bbb		0.15			
ссс	0.08				
ddd		0.10			
eee	0.05				

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

Si566 Data Sheet • Package Outline

#### 5.3 Package Outline (2.5x3.2 mm)

The figure below illustrates the package details for the 2.5x3.2 mm Si566. The table below lists the values for the dimensions shown in the illustration.

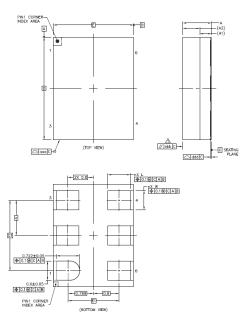


Figure 5.3. Si566 (2.5×3.2 mm) Outline Diagram

Table 5.3. Package Diagram Dimensions (mm
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Dimension	Min	Nom	Мах		
A	0.90 0.95 1.00				
A1	0.36 REF				
A2	0.53 REF				
W	0.55 0.60 0.65				
D	3.2 BSC				
E	2.5 BSC				
e	1.10 BSC				
L	0.65 0.70 0.75				
n	5				
D1	2.2 BSC				
E1	1.589 BSC				
ааа	0.10				
bbb		0.10			
ddd		0.08			
Notes:					

#### Notes:

1. The dimensions in parentheses are reference.

2. All dimensions in millimeters (mm).

3. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

Si566 Data Sheet • PCB Land Pattern

## 6. PCB Land Pattern

#### 6.1 PCB Land Pattern (5×7 mm)

The figure below illustrates the 5×7 mm PCB land pattern for the Si566. The table below lists the values for the dimensions shown in the illustration.

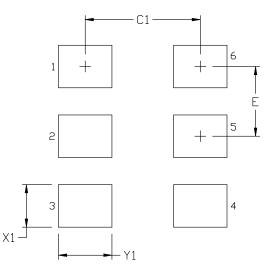


Figure 6.1. Si566 (5×7 mm) PCB Land Pattern

#### Table 6.1. PCB Land Pattern Dimensions (mm)

Dimension	(mm)
C1	4.20
E	2.54
X1	1.55
Y1	1.95

Notes:

#### General

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
- 3. This Land Pattern Design is based on the IPC-7351 guidelines.
- 4. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

#### Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

#### Stencil Design

- 1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
- 2. The stencil thickness should be 0.125 mm (5 mils).
- 3. The ratio of stencil aperture to land pad size should be 1:1.

#### Card Assembly

- 1. A No-Clean, Type-3 solder paste is recommended.
- 2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

Si566 Data Sheet • PCB Land Pattern

#### 6.2 PCB Land Pattern (3.2×5 mm)

The figure below illustrates the 3.2×5.0 mm PCB land pattern for the Si566. The table below lists the values for the dimensions shown in the illustration.

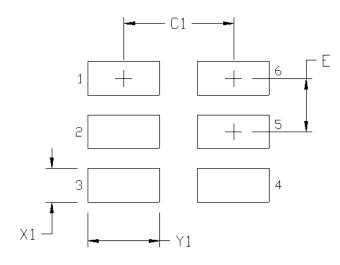


Figure 6.2. Si566 (3.2×5 mm) PCB Land Pattern

#### Table 6.2. PCB Land Pattern Dimensions (mm)

Dimension	(mm)
C1	2.60
E	1.27
X1	0.80
Y1	1.70

#### Notes:

#### General

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
- 3. This Land Pattern Design is based on the IPC-7351 guidelines.
- 4. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

#### Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

#### Stencil Design

- 1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
- 2. The stencil thickness should be 0.125 mm (5 mils).
- 3. The ratio of stencil aperture to land pad size should be 1:1.

#### **Card Assembly**

- 1. A No-Clean, Type-3 solder paste is recommended.
- 2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

Si566 Data Sheet • PCB Land Pattern

#### 6.3 PCB Land Pattern (2.5×3.2 mm)

The figure below illustrates the 2.5×3.2 mm PCB land pattern for the Si566. The table below lists the values for the dimensions shown in the illustration.

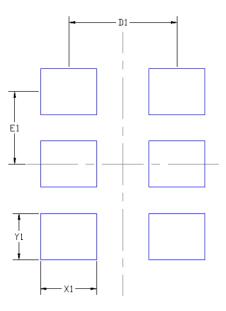


Figure 6.3. Si566 (2.5×3.2 mm) PCB Land Pattern

#### Table 6.3. PCB Land Pattern Dimensions (mm)

Dimension	Description	Value (mm)
X1	Width - leads on long sides	0.85
Y1	Height - leads on long sides	0.7
D1	Pitch in X directions of XLY1 leads	1.639
E1	Lead pitch XLY1 leads	1.10

**Notes:** The following notes and stencil design are shared as recommendations only. A customer or user may find it necessary to use different parameters and fine-tune their SMT process as required for their application and tooling.

#### General

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
- 3. This Land Pattern Design is based on the IPC-7351 guidelines.
- 4. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

#### Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

#### Stencil Design

- 1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
- 2. The stencil thickness should be 0.125 mm (5 mils).
- 3. The ratio of stencil aperture to land pad size should be 0.8:1 for the pads.

#### **Card Assembly**

- 1. A No-Clean, Type-3 solder paste is recommended.
- 2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

Si566 Data Sheet • Top Markings

## 7. Top Markings

#### 7.1 Top Marking (5x7 and 3.2x5 Packages)

The figure below illustrates the mark specification for the Si566 5x7 and 3.2x5 package sizes. The table below lists the line information.

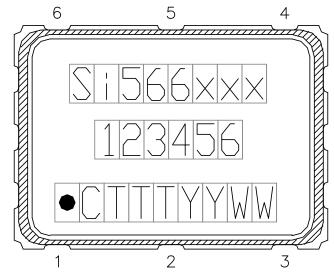


Figure 7.1. Mark Specification

Table 7.1.	Si566	Тор	Mark	Description
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Line	Position	Description
1	1–8	"Si566", xxx = Ordering Option 1, Option 2, Option 3 (e.g. Si566AAA)
2	1–6	Frequency Code (6-digit custom code as described in the Ordering Guide)
3	Trace Code	
	Position 1	Pin 1 orientation mark (dot)
	Position 2	Product Revision (C)
-	Position 3–5	Tiny Trace Code (3 alphanumeric characters per assembly release instructions)
	Position 6–7	Year (last two digits of the year), to be assigned by assembly site (ex: 2017 = 17)
	Position 8–9	Calendar Work Week number (1–53), to be assigned by assembly site

#### 7.2 Top Marking (2.5x3.2 Package)

The figure below illustrates the mark specification for the Si566 2.5x3.2 package sizes. The table below lists the line information.

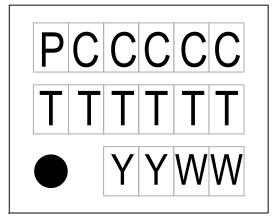


Figure 7.2. Mark Specification

#### Table 7.2. Si566 Top Mark Description

Line	Position	Description	
1	1–6	P = Si566, CCCCC = Custom Mark Code	
2	Trace Code		
	1–6	Six-digit trace code per assembly release instructions	
3 Position 1		Pin 1 orientation mark (dot)	
	Position 2–3	Year (last two digits of the year), to be assigned by assembly site (exp: 2017 = 17)	
	Position 4–5	Calendar Work Week number (1–53), to be assigned by assembly site	

Si566 Data Sheet • Revision History

## 8. Revision History

#### **Revision 1.3**

June, 2021

- Updated Ordering Guide and Top Mark for Rev C silicon.
- Added HCSL-Fast (faster t<sub>R</sub>/t<sub>F</sub>) ordering option.
- Updated Table 2.1, Powerup VDD Ramp Rate.

#### **Revision 1.2**

September, 2020

- Added 2.5 x 3.2 mm package option.
- Updated Table 2.1, Powerup VDD Ramp Rate and LVDS Swing.

#### **Revision 1.0**

June, 2018

· Initial draft

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